

# GR-65P075KT: TO-220-3L Cascode GaN HEMT

### **Description**

GR-65P075KT is a normally-off GaN High electron mobility transistor (HEMT) device using the cascode configuration, which provides high breakdown voltage, high current and high operating speed which is suitable for high power applications.

## **Key Specifications**

Part Number	GR-65P075KT
V <sub>DSS</sub> , min.	650V
R <sub>DS(ON)</sub> , typ.	74mΩ
Package	TO-220-3L

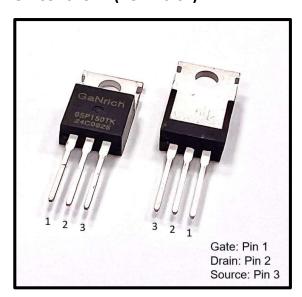
#### **Features**

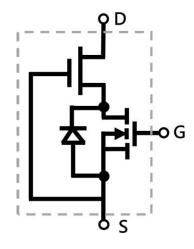
- Gate drive voltage compatibility (-20V to +20V)
- · High operating frequency
- Pin to Pin with CoolMOS/SJ and SiC MOSFET
- Low Qrr

## **Applications**

- Switch Mode Power Supplies (SMPS)
- AC-DC/ DC-DC Converters
- Motor Drives

### GR-65P075KT (TO-220-3L)





**Cascode Device Structure**